











LMH2832 SBOS709A - JULY 2016-REVISED JULY 2016

LMH2832 Fully Differential, Dual, 1.1-GHz, Digital Variable-Gain Amplifier

Features

- Dual-Channel, Individual SPI™-Controlled DVGA
- Single 5-V Supply
- -3-dB Bandwidth: 1.1 GHz (Max Gain)
- Flat Bandwidth Response: 300 MHz
- Channel-to-Channel Gain Matching: ±0.05 dB
- Channel-to-Channel Phase Matching: ±0.1°
- Gain:
 - 30 dB to –9 dB
 - 1-dB Steps ±0.2 dB
- Output Third-Order Intercept Point (OIP3):
 - 43 dBm at 300 MHz
 - 51 dBm at 200 MHz
- Noise Figure (NF):
 - 6.5 dB (Max Gain) at 300 MHz, Z_{IN} = 150 Ω
- Adjustable Power Consumption:
 - 90 mA to 108 mA per Channel
- Power-Saving, Power-Down Feature:
 - I_O < 4.5 mA per Channel
 - Power-Down Pin and SPI Programmability
- Input Return Loss at 300 MHz:
 - 17 dB (R_S = 150 Ω)

2 Applications

- DOCSIS 3.1 CMTS Upstream Direct Sampling Receivers
- CATV Modem Signal Scaling
- Programmable Gain IF Amplifiers
- Generic RF, IF Gain Stages
- **ADC Drivers**

3 Description

The LMH2832 is a high-linearity, dual-channel, digital variable-gain amplifier (DVGA) for high-speed signal chain and data-acquisition systems. The LMH2832 is optimized to provide high bandwidth, low distortion, and low noise, thus making the device ideally suited as a dual, 14-bit, analog-to-digital converter (ADC) driver. The device consists of one fixed-gain block and one variable attenuator consisting of a total gain of 30 dB with a maximum attenuation of 39 dB. The gain range is from 30 dB to -9 dB in 1-dB gain steps with a gain accuracy of ±0.2 dB. The input impedance can be easily matched to $50-\Omega$ or $75-\Omega$ systems using a 1:3- Ω or 1:2- Ω ratio balun, respectively. The LMH2832 is designed to drive general-purpose ADCs and also meets the requirements for both data over cable service interface specification (DOCSIS) 3.0 32 quadrature amplitude modulation (QAM) carriers and DOCSIS 3.1 wideband orthogonal frequency-division multiplexing (OFDM) systems. With excellent NF (6.5 dB) and linearity, the LMH2832 is designed to perform to within DOCSIS specifications. quiescent current in the power-down state is less than 5 mA per channel with the typical current consumption during operation at 105 mA per channel.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
LMH2832	VQFN (40)	6.00 mm × 6.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Output Third-Order Intercept Point (OIP3) Performance

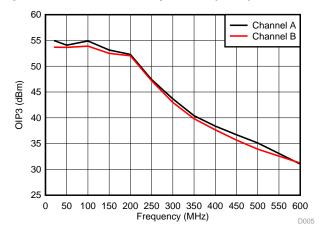




Table of Contents

1	Features 1		9.1 Overview	
2	Applications 1		9.2 Functional Block Diagram	19
3	Description 1		9.3 Feature Description	19
4	Revision History2		9.4 Device Functional Modes	21
5	Device Comparison Table		9.5 Programming	
6	Pin Configuration and Functions		9.6 Register Maps	
7	Specifications 5	10	Application and Implementation	29
•	7.1 Absolute Maximum Ratings 5		10.1 Application Information	29
	7.2 ESD Ratings		10.2 Typical Applications	32
	<u> </u>		10.3 Do's and Don'ts	35
	7.3 Recommended Operating Conditions	11	Power Supply Recommendations	35
	7.5 Electrical Characteristics 6		11.1 Split Supplies	
			11.2 Supply Decoupling	35
		12	Layout	36
			12.1 Layout Guidelines	
8	Parameter Measurement Information		12.2 Layout Example	
	8.1 Setup Diagrams	13	Device and Documentation Support	
	8.2 ATE Testing and DC Measurements		13.1 Device Support	
	8.3 Frequency Response		13.2 Documentation Support	
	8.4 Distortion		13.3 Receiving Notification of Documentation Update	
	8.5 Noise Figure		13.4 Community Resources	
	8.6 Pulse Response, Slew Rate, and Overdrive		13.5 Trademarks	
	Recovery		13.6 Electrostatic Discharge Caution	
	8.7 Power-Down		13.7 Glossary	
	8.8 Crosstalk, Gain Matching, and Phase Matching 18	44	•	36
	8.9 Output Measurement Reference Points	14	Mechanical, Packaging, and Orderable Information	20
9	Detailed Description 19		IIIIOIIIIauoii	38

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (July 2016) to Revision A

Page

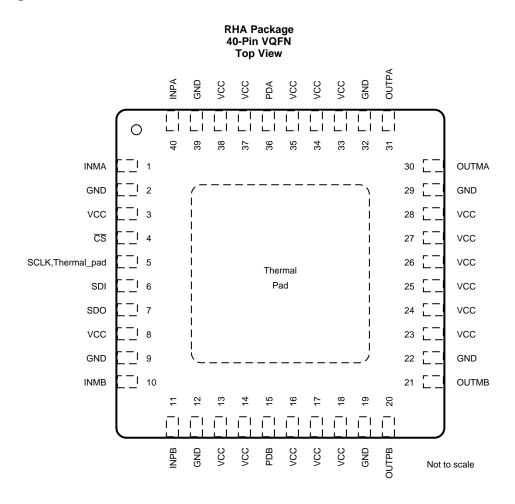


5 Device Comparison Table

Table 1. DVGA Device Comparison

DEVICE	MAX GAIN, BW	DISTORTION	NOISE FIGURE
LMH6401	26 dB, 4.5 GHz	43-dBm OIP3 at 200 MHz, -80-dBc HD3 at 200 MHz	7.7 dB
LHM6517	22 dB, 1.2 GHz	43-dBm OIP3 at 200 MHz, -74-dBc HD3 at 200 MHz	5.5 dB
LMH6521	26 dB, 1.2 GHz	49-dBm OIP3 at 200 MHz, -84-dBc HD3 at 200 MHz	7.3 dB
LMH6881	26 dB, 2.4 GHz	42-dBm OIP3 at 200 MHz, -76-dBc HD3 at 200 MHz	9.7 dB

6 Pin Configuration and Functions





Pin Functions

	PIN	1/0	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
CS	4	I	Serial interface enable, active low
GND	2, 9, 12, 19, 22, 29, 32, 39	1	Analog ground
INMA	1	1	Negative differential input, channel A
INMB	10	1	Negative differential input, channel B
INPA	40	I	Positive differential input, channel A
INPB	11	I	Positive differential input, channel B
OUTMA	30	0	Negative differential output, channel A
OUTMB	21	0	Negative differential output, channel B
OUTPA	31	0	Positive differential output, channel A
OUTPB	20	0	Positive differential output, channel B
PDB	15	I	Power-down control, channel B (logic high = power-down)
PDA	36	I	Power-down control, channel A (logic high = power-down)
SCLK	5	I	Serial interface clock input
SDI	6	I	Serial interface data input
SDO	7	0	Serial interface data output
VCC	3, 8, 13, 14, 16, 17, 18, 23, 24, 25, 26, 27, 28, 33, 34, 35, 37, 38	I	Analog voltage supply
Thermal pad		_	Connected to ground



7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Power supply	-0.5	5.5	V	
Input applied to analog inputs	INPA, INMA, INPB, INMB	-0.5	5.5	V
Voltage applied to input pins	•	-0.5	5.5	V
Digital input/output voltage range	-0.3	2	V	
Operating junction temperature, T _J		125	°C	
Storage temperature, T _{stg}	-40	125	°C	

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

			VALUE	UNIT
.,		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	.,
V _{(ES}	SD) Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
Vs	Power-supply voltage	4.75	5	5.25	V
	Specified operating temperature range	-40		85	°C

7.4 Thermal Information

		LMH2832	
	THERMAL METRIC ⁽¹⁾		UNIT
		40 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	29.5	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	20.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	6.6	°C/W
ΨЈТ	Junction-to-top characterization parameter	0.3	°C/W
ΨЈВ	Junction-to-board characterization parameter	6.5	°C/W
R ₀ JC(bot)	Junction-to-case (bottom) thermal resistance	2.3	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report (SPRA953).

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.5 Electrical Characteristics

at $T_A = 25^{\circ}\text{C}$, $V_{S+} = 5 \text{ V}$, $R_i = 75 \Omega$, $R_L = 150 \Omega$, maximum gain (1:2- Ω ratio transformer plus 30-dB DVGA gain), f = 5 MHz to 300 MHz, V_O converted to single-ended (SE) measurement with a transformer, and default current setting (unless otherwise noted); upon power-up, gain is set to mid-range

	PARAMETER	TEST CONDITIONS	MIN TYP	P MAX	UNIT	TEST LEVEL ⁽¹⁾
AC PER	FORMANCE					
LSBW	Large-signal,	$G = 30 \text{ dB}, V_O = 2 V_{PP}$	1140)	MHz	С
LSDW	–3-dB bandwidth	$G = 0 dB$, $V_O = 2 V_{PP}$	2350)	IVITZ	С
BW	Bandwidth for 0.1-dB flatness		300)	MHz	С
	Second-order harmonic distortion	$f = 100 \text{ MHz}, V_O = 2 V_{PP}$	-88	3		С
HD2		$f = 200 \text{ MHz}, V_O = 2 V_{PP}$	-70	6	dBc	С
пи		$f = 300 \text{ MHz}, V_O = 2 V_{PP}$	-63	3	UDC	С
		$f = 450 \text{ MHz}, V_O = 2 V_{PP}$	-58	3		С
		f = 100 MHz, V _O = 2 V _{PP}	-94	4		С
LIDO	Third-order harmonic	f = 200 MHz, V _O = 2 V _{PP}	-90)	dD.c	С
HD3	distortion	$f = 300 \text{ MHz}, V_O = 2 V_{PP}$	-8	1	dBc	С
		$f = 450 \text{ MHz}, V_O = 2 V_{PP}$	-79	5		С
	Third-order intermodulation	f = 100 MHz, tone spacing = 2 MHz, $P_{OUT}^{(2)} = 0$ dBm per tone	-100	6		С
IMD3	distortion	f = 200 MHz, tone spacing = 2 MHz	-102	2	dBc	С
		f = 300 MHz, tone spacing = 2 MHz	-80	6		С
	Output third-order intercept point	f = 100 MHz, tone spacing = 2 MHz, P _{OUT} = 0 dBm per tone	53	3		С
OIP3		f = 200 MHz, tone spacing = 2 MHz, P _{OUT} = 0 dBm per tone	5	1	dBm	С
		f = 300 MHz, tone spacing = 2 MHz, P _{OUT} = 0 dBm per tone	43	3		С
		$f = 100 \text{ MHz}, R_L = 150 \Omega$	10	6		С
P1dB	1-dB compression point	$f = 200 \text{ MHz}, R_L = 150 \Omega$	10	6	dBm	С
		$f = 300 \text{ MHz}, R_L = 150 \Omega$	16.9	5		С
NF	Noise figure	R_i = 150 Ω , f = 300 MHz, max gain	6.9	5	dB	С
	Output-referred voltage noise	f = 300 MHz, max gain	47.7	7	nV/√Hz	С
S11	Input return loss	f = 300 MHz	17	7	dB	С
S22	Reverse Isolation	Including input transformer, f < 300 MHz	53	3	dB	С
	Channel-to-channel crosstalk	f = 300 MHz, channel A to B	-77	7	dB	С
	Charmer-to-charmer crosstalk	f = 300 MHz, channel B to A	-8	1	uБ	C
	Channel-to-channel phase matching	f = 200 MHz	±0.	1	0	С
	Channel-to-channel gain matching	f = 200 MHz	±0.09	5	dB	С
GAIN PA	ARAMETERS					
	Maximum voltage gain	f = dc, gain code = 00h	29.5 30	30.5	dB	Α
	Minimum voltage gain	f = dc, gain code = 27h	-9.5 - 9	9 –8.5	dB	А
	Gain range		39	9	dB	С
	Gain step size	Between any two adjacent gain settings	0.75	1 1.25	dB	Α
E _G	Gain error	For any gain value	-0.5	0.5	dB	Α
	Cumulative gain error	Referenced to max gain	-1	1	dB	Α
	Gain step transition time		(3	ns	С

⁽¹⁾ Test levels: (A) 100% tested at 25°C. Overtemperature limits by characterization and simulation. (B) Limits set by characterization and simulation. (C) Typical value only for information.

⁽²⁾ P_{OUT} is the signal tone power at the output of the device.



Electrical Characteristics (continued)

at T_A = 25°C, V_{S+} = 5 V, R_i = 75 Ω , R_L = 150 Ω , maximum gain (1:2- Ω ratio transformer plus 30-dB DVGA gain), f = 5 MHz to 300 MHz, V_O converted to single-ended (SE) measurement with a transformer, and default current setting (unless otherwise noted); upon power-up, gain is set to mid-range

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	TEST LEVEL ⁽¹⁾
ANALOG	INPUT CHARACTERISTICS				1		
z _{in}	Input resistance	f = dc, differential	135	150	165	Ω	Α
C _{in}	Input capacitance	Differential		0.6		pF	С
	Single-ended input resistance	f = dc	67.5	75	82.5	Ω	Α
	Single-ended input capacitance			1.2		pF	С
V _{ICM}	Input common-mode voltage	Internally biased to mid-supply	-0.2		0.2	V	Α
V_{IL}	Low-level input voltage range	Differential gain shift < 1 dB	(V _S	₃ _) + 1.5		V	С
V _{IH}	High-level input voltage range	Differential gain shift < 1 dB	(V _S	_{S+}) – 1.5		V	С
ANALOG	OUTPUT CHARACTERISTICS						
Z _O	Output resistance	Differential		20		Ω	С
V_{OL}	Low-level output voltage range	V _S = 5 V, GND = 0 V		1.15	1.25	٧	А
V_{OH}	High-level output voltage range	V _S = 5 V, GND = 0 V	3.75	3.85		V	А
V	Maximum output voltage swing	T _A = 25°C	5	5.4		V	Α
V_{OM}		$T_A = -40$ °C to +85°C		5.4	6.4	V	В
CMRR	Common-mode rejection ratio			56		dB	С
POWER	SUPPLY						
V _S	Supply voltage		4.75	5.0	5.25	V	Α
	Quiescent current per channel	Default current, default bias setting	102	105	108	mA	Α
I_Q		Min current, lowest power setting		90			С
		Max current, highest bias setting		108			С
±PSRR	Power-supply rejection ratio (3)	Gain = 30 dB		-48		dB	С
POWER-	-DOWN ⁽⁴⁾						
	Power-down quiescent current	T _A = 25°C		2.5	6	Δ	Α
	(per channel)	$T_A = -40$ °C to +85°C			6.5	mA	В
	Power-down bias current		-2	-1		μΑ	Α
	Turn-on time delay	Time to $V_0 = 90\%$ of final value, gain = 0 dB, $V_1 = 2 \text{ V}$		55		ns	С
	Turn-off time delay	Time to $V_0 = 10\%$ of original value, gain = 0 dB, $V_1 = 2 \text{ V}$		110		ns	С
	Forward isolation in PD mode	f = 300 MHz		-67		dB	С
DIGITAL	INPUTS/OUTPUTS						
V _{IH}	High-level input voltage		1.4		2	٧	Α
V _{IL}	Low-level input voltage -0.3 0.8		0.8	V	Α		
	TP-sh Tarrell and the P	I _{OH} = -100 μA	1.65				Α
V_{OH}	High-level output voltage	I _{OH} = −2 mA	1.55			V	Α
.,	Laurelanda et al	I _{OL} = 100 μA			0.1		Α
V_{OL}	Low-level output voltage	I _{OL} = 2 mA			0.2	V	Α

⁽³⁾ PSRR is defined with respect to a differential output.

⁽⁴⁾ The device power-down function can be controlled by the PDx pins or by the power-down register accessible from the SPI interface.



7.6 Timing Requirements: SPI

		MIN	TYP	MAX	UNIT
f _{S_C}	SCLK frequency ⁽¹⁾	0	25	50	MHz
t _{PH}	SCLK pulse duration, high		10		ns
t _{PL}	SCLK pulse duration, low		10		ns
t _{SU}	SDI setup		3		ns
t _H	SDO hold		3		ns
t_{IZ}	SDO tri-state		3		ns
t _{ODZ}	SDO driven to tri-state (2)	0	10	20	ns
t _{OZD}	SDO tri-state to driven	0	2	5	ns
t _{OD}	SDO output delay ⁽²⁾	0	10	12	ns
t _{CSS}	CS setup ⁽³⁾	3	5		ns
t _{CSH}	CS hold		3		ns
t _{IAG}	Inter-access gap		20		ns

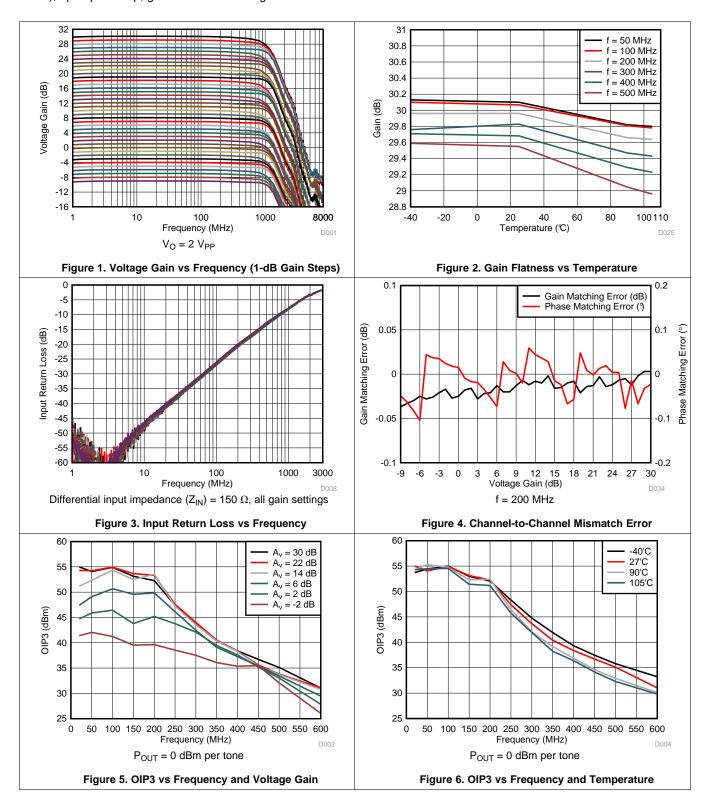
Tested on the automated test equipment (ATE) only up to 25 MHz.
 Referenced to the negative edge of SCLK.
 Referenced to the positive edge of SCLK.

Submit Documentation Feedback



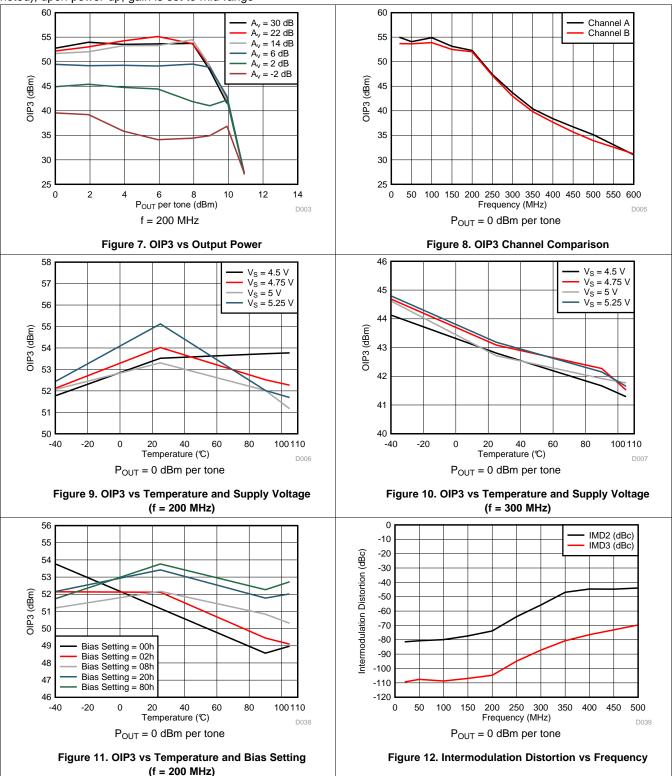
7.7 Typical Characteristics

at $T_A = 25$ °C, $V_{S+} = 5$ V, $R_i = 75$ Ω , $R_L = 150$ Ω , maximum gain (1:2- Ω ratio transformer plus 30-dB DVGA gain), f = 5 MHz to 300 MHz, V_O converted to single-ended (SE) measurement with transformer, and default current setting (unless otherwise noted); upon power-up, gain is set to mid-range





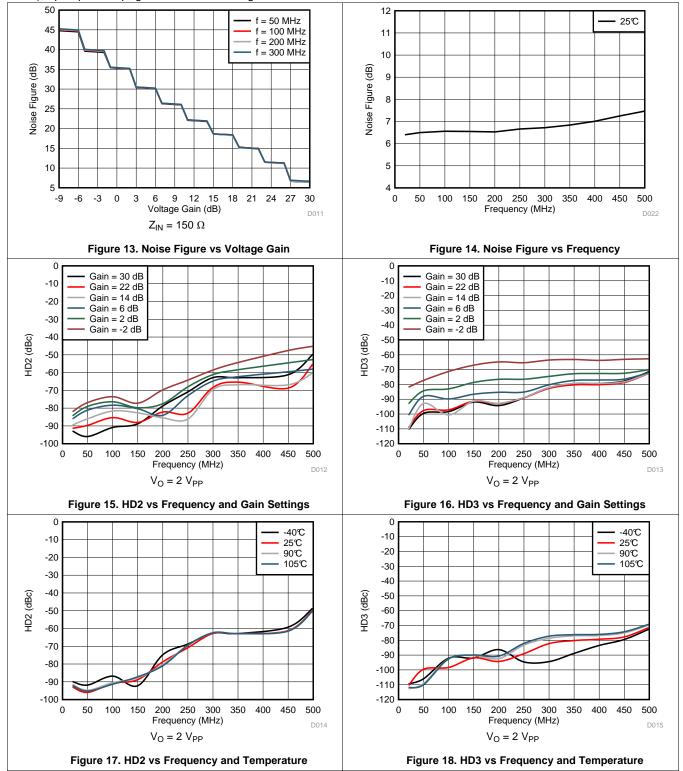
at $T_A = 25$ °C, $V_{S+} = 5$ V, $R_i = 75$ Ω , $R_L = 150$ Ω , maximum gain (1:2- Ω ratio transformer plus 30-dB DVGA gain), f = 5 MHz to 300 MHz, V_O converted to single-ended (SE) measurement with transformer, and default current setting (unless otherwise noted); upon power-up, gain is set to mid-range



Submit Documentation Feedback



at $T_A = 25$ °C, $V_{S+} = 5$ V, $R_i = 75$ Ω , $R_L = 150$ Ω , maximum gain (1:2- Ω ratio transformer plus 30-dB DVGA gain), f = 5 MHz to 300 MHz, V_O converted to single-ended (SE) measurement with transformer, and default current setting (unless otherwise noted); upon power-up, gain is set to mid-range

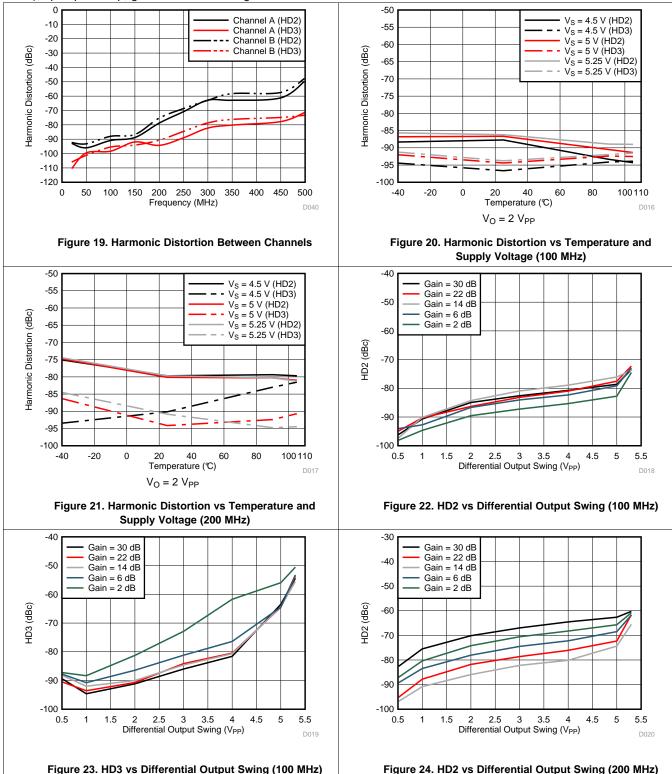


Copyright © 2016, Texas Instruments Incorporated

Submit Documentation Feedback



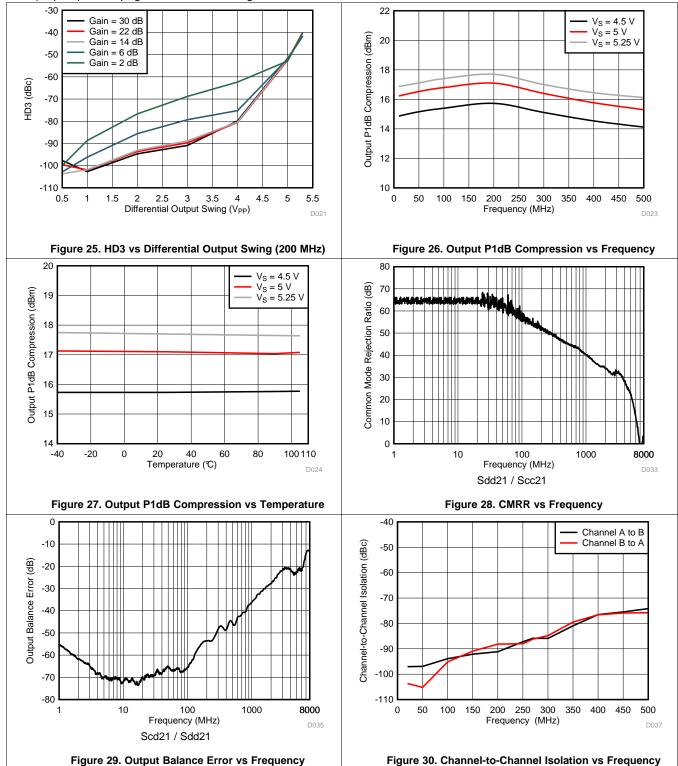
at $T_A = 25$ °C, $V_{S+} = 5$ V, $R_i = 75$ Ω , $R_L = 150$ Ω , maximum gain (1:2- Ω ratio transformer plus 30-dB DVGA gain), f = 5 MHz to 300 MHz, V_O converted to single-ended (SE) measurement with transformer, and default current setting (unless otherwise noted); upon power-up, gain is set to mid-range



Submit Documentation Feedback

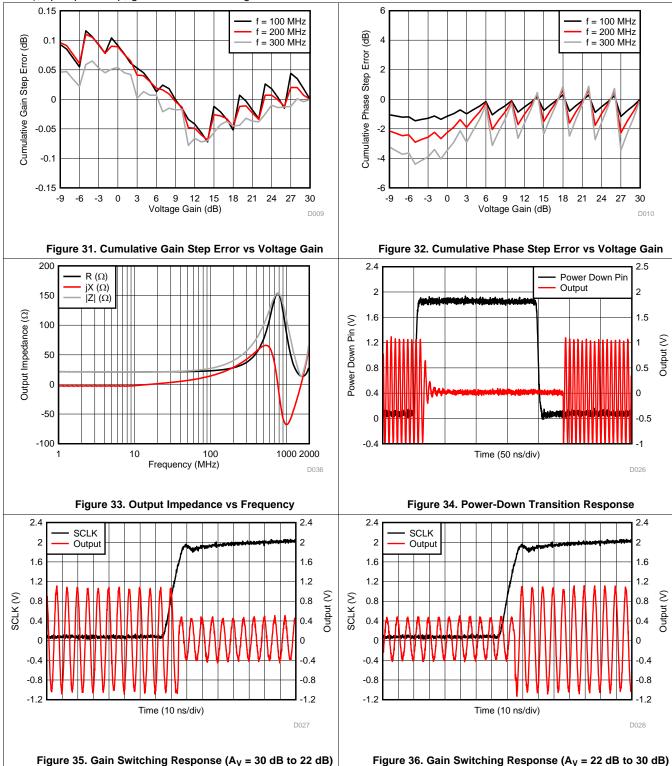


at T_A = 25°C, V_{S+} = 5 V, R_i = 75 Ω , R_L = 150 Ω , maximum gain (1:2- Ω ratio transformer plus 30-dB DVGA gain), f = 5 MHz to 300 MHz, V_O converted to single-ended (SE) measurement with transformer, and default current setting (unless otherwise noted); upon power-up, gain is set to mid-range





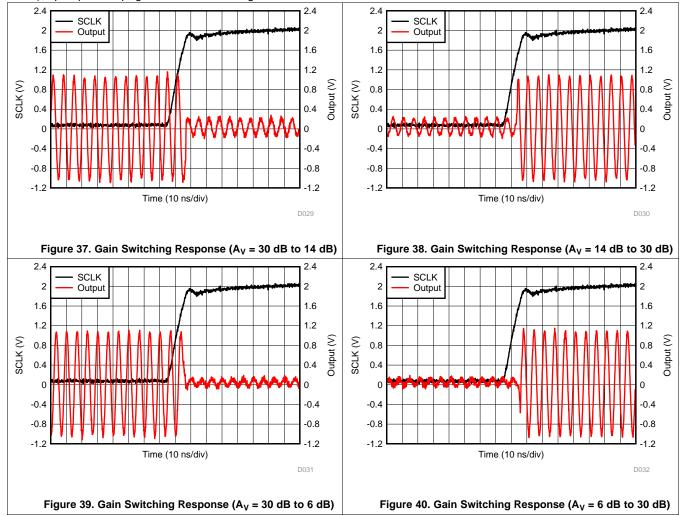
at T_A = 25°C, V_{S+} = 5 V, R_i = 75 Ω , R_L = 150 Ω , maximum gain (1:2- Ω ratio transformer plus 30-dB DVGA gain), f = 5 MHz to 300 MHz, V_O converted to single-ended (SE) measurement with transformer, and default current setting (unless otherwise noted); upon power-up, gain is set to mid-range



Submit Documentation Feedback



at $T_A = 25^{\circ}\text{C}$, $V_{S+} = 5 \text{ V}$, $R_i = 75 \Omega$, $R_L = 150 \Omega$, maximum gain (1:2- Ω ratio transformer plus 30-dB DVGA gain), f = 5 MHz to 300 MHz, V_O converted to single-ended (SE) measurement with transformer, and default current setting (unless otherwise noted); upon power-up, gain is set to mid-range





8 Parameter Measurement Information

8.1 Setup Diagrams

Figure 41 to Figure 44 illustrate various test setup diagrams using the LMH2832 evaluation module (EVM).

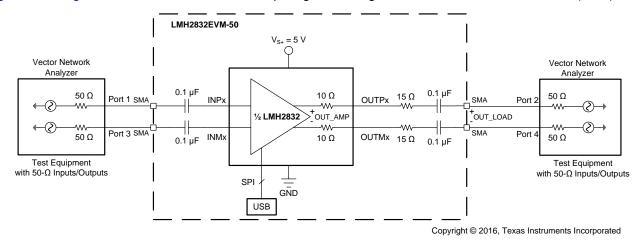


Figure 41. Frequency Response Differential Test Setup

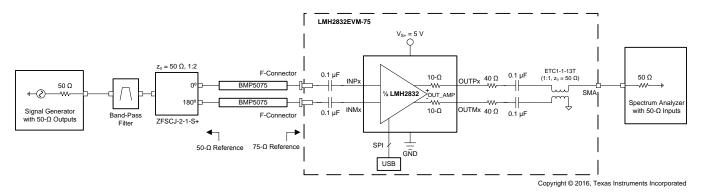


Figure 42. Single-Tone Harmonic Distortion Test Setup

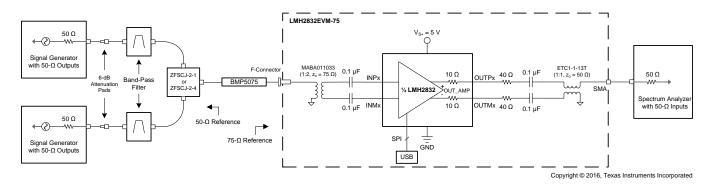


Figure 43. Two-Tone Linearity Test Setup (OIP3, OIP2)



Setup Diagrams (continued)

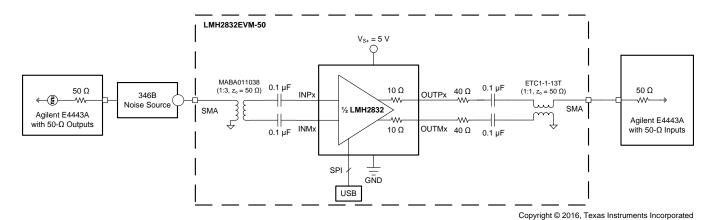


Figure 44. Noise Figure Test Setup

8.2 ATE Testing and DC Measurements

All production testing and dc parameters are measured on automated test equipment (ATE) capable of dc measurements only. Some measurements (such as voltage gain) are referenced to the output of the internal amplifier and do not include losses attributed to the on-chip output resistors. The *Electrical Characteristics* values specify these conditions. When the measurement is referred to the amplifier output, the output resistors are not included in the measurement. If the measurement is referred to the device pins, then the output resistor loss is included in the measurement.

8.3 Frequency Response

This test is done by running an S-parameter sweep on a 4-port differential network analyzer using the standard EVM with no baluns; see Figure 41. The inputs and outputs of the EVM are connected to the network analyzer using 75- Ω coaxial cables with the input ports set to a characteristic impedance of 75 Ω , and the output ports set to a characteristic impedance of 50 Ω .

The frequency response test with capacitive load is done by soldering the capacitor across the LMH2832 output pins. In this configuration, the on-chip, $10-\Omega$ resistors on each output leg isolate the capacitive load from the amplifier output pins.

8.4 Distortion

The standard EVM is used for measuring both the single-tone harmonic distortion and two-tone intermodulation distortion; see Figure 42 and Figure 43, respectively. The distortion is measured with differential input signals to the LMH2832. In order to interface with $50-\Omega$, single-ended test equipment, $50-\Omega$ to $75-\Omega$ impedance matching pads followed by external baluns (1:2, $z_0 = 75~\Omega$) are required between the EVM output ports and the test equipment. These baluns are used to combine two single tones in the two-tone test plots as well as to convert the single-ended input to differential output for harmonic distortion tests. The use of 6-dB attenuator pads on both the inputs and outputs is recommended to provide a balanced match between the external balun and the EVM.

8.5 Noise Figure

This test is done by matching the input of the LMH2832 to a 50- Ω noise source using a 50- Ω to 75- Ω impedance transformation pad followed by a 1:2 balun (Figure 44), with the noise figure being referred to the input impedance (R_S = 150 Ω). As noted in Figure 44, a Keysight TechnologiesTM E4443A with NF features is used for the testing.



8.6 Pulse Response, Slew Rate, and Overdrive Recovery

For time-domain measurements, the standard EVM is driven through an impedance transformation pad and a balun again to convert a single-ended output from the test equipment to the differential inputs of the LMH2832. The differential outputs are directly connected to the oscilloscope inputs, with the differential signal response calculated using trace math from the two separate oscilloscope inputs.

8.7 Power-Down

The standard EVM is used for this test by completely removing the shorting block on jumper JPD. A high-speed, $50-\Omega$ pulse generator is used to drive the PDx pin that toggles the output signal on or off depending upon the PDx pin voltage.

8.8 Crosstalk, Gain Matching, and Phase Matching

The standard EVM is used for these tests with both channels enabled. For gain and phase matching, the responses of both channels are measured on a network analyzer and the gain and phase values are compared. For crosstalk, a single channel is driven with a signal on the network analyzer when the other channel is measured.

8.9 Output Measurement Reference Points

The LMH2832 has two on-chip, $10-\Omega$ output resistors on each channel. When matching the output to a $100-\Omega$ load, the evaluation module (EVM) uses an external $40-\Omega$ resistor on each output leg to complete the output matching. The inclusion of on-chip output resistors creates two potential reference points for measuring the output voltage. The first reference point is at the internal amplifier output (OUT_AMP), and the second reference point is at the externally-matched $100-\Omega$ load (OUT_LOAD). The measurements in the *Electrical Characteristics* table and in the *Typical Characteristics* section are referred to the (OUT_AMP) reference point unless otherwise specified. The conversion between reference points is a straightforward correction of 3 dB for power and 6 dB for voltage, as shown in Equation 1 and Equation 2. The measurements are referenced to OUT_AMP when not specified.

$$VOUT_LOAD = (VOUT_AMP - 6 dB)$$
 (1)

$$POUT_LOAD = (POUT_AMP - 3 dB)$$
 (2)

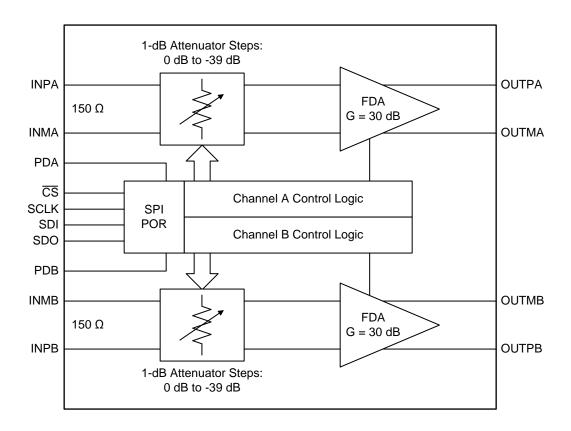


9 Detailed Description

9.1 Overview

Each channel of the LMH2832 consists of an input attenuator block followed by a fully differential amplifier that has a gain of 30 dB. The attenuator has a range of 0 dB to -39 dB in 1-dB steps that is controlled by an SPI interface. The two channels can be controlled independently using the digital interface including power-down and bias settings. A separate analog power-down pin (PDA, PDB) is also included for each channel so that the device can bet set to a low-power state without waiting for a serial write to a register. The internal registers also include a power-on-reset (POR) that ensures the device starts in a known state after the power is reset.

9.2 Functional Block Diagram



9.3 Feature Description

9.3.1 Analog Input Characteristics

The LMH2832 is a dual-channel device with two identical channels (A and B) that each have differential input pins (INP and INM) that denote the positive and negative inputs, respectively. The inputs are expected to be accoupled only, typically through a transformer or capacitor. The amplifier self-biases the input common-mode to mid-supply for the maximum input voltage range. The inputs of the LMH2832 can only be driven differentially. For single-ended input source applications, use a balun or fully differential amplifier (such as the LMH3401 or LMH5401) that can convert single-ended to differential signals before the LMH2832.



Feature Description (continued)

At maximum gain, the digital attenuator is set to 0 dB of attenuation, causing the input signal to be much larger than the output signal and forcing the maximum output voltage swing to be limited by the outputs of the device. However at minimum gain, the maximum voltage swing is limited by the inputs of the device because the attenuator causes the output voltage to be 9 dB lower than the input voltage. In minimum gain, the input voltage limits against the electrostatic discharge (ESD) devices before the output reaches the maximum swing limits. For linear operation, the input voltage must be kept within the maximum input voltage ratings described in the *Electrical Characteristics* table.

The input impedance of the LMH2832 is set by internal termination resistors to a nominal value of 150 Ω , differential. Process variations result in a range of values, as described in the *Electrical Characteristics* table. The input impedance is also affected by device parasitic effects at higher frequencies that cause the impedance to shift away from the nominal value.

9.3.2 Analog Output Characteristics

The LMH2832 has series, $10-\Omega$, on-chip resistors on each output to provide isolation from board parasitics that can cause instability. When designing a filter following the LMH2832, the filter source impedance calculation must include the two $10-\Omega$, on-chip resistors. Table 2 shows the calculated external source impedance values required for various matched filter loads.

Table 2. Output Resistor Values for Matched Loads

MATCHED FILTER IMPEDANCE (Ω)	EXTERNAL SERIES RESISTOR PER OUTPUT (Ω)
100	80
150	130
200	180
300	280

9.3.3 Driving Low Insertion-Loss Filters

When driving high-speed ADCs, a filter is commonly driven with a matched impedance to the ADC. This impedance is matched by the amplifier by setting the combination of the output resistors to the same impedance as the ADC inputs. Impedance matching is often done to minimize any transmission reflections caused by the physical signal path. The drawback to using a matched impedance is that a voltage swing is required from the amplifier outputs that is twice the desired ADC input voltage swing, which can cause output voltage limitation issues.

To avoid using a matched impedance, a low insertion loss filter can be driven where there is little to no resistance added at the amplifier outputs. The amplifier outputs then only must swing to the value of the ADC full-scale input voltage, thus eliminating most of the potential amplifier output headroom issues. The requirements of this technique are that the amplifier must be able to provide enough current to the load of the ADC and that the path between the amplifier outputs and ADC inputs must be minimized to prevent any reflections.

9.3.4 Input Impedance Matching

The LMH2832 has a differential input impedance of 150 Ω that can be easily matched to single-ended, 50- Ω or 75- Ω systems using baluns. For a single-ended, 50- Ω input, a 1:3- Ω ratio balun can be used to create a 150- Ω differential source impedance to the device with a balun gain of 4.8 dB. For a single-ended, 75- Ω input, a 1:2- Ω ratio balun creates a 150- Ω differential source impedance to the device with a voltage gain of 3 dB.

9.3.5 Power-On Reset (POR)

The LMH2832 has a built-in, power-on-reset (POR) that sets the device registers to their default state (see the *Register Maps* section) on power-up. Note that the LMH2832 register information is lost when power is removed. When power is reapplied, the POR ensures that the device enters a default state. Power glitches (of sufficient duration) can also initiate the POR and return the device to a default state.



9.4 Device Functional Modes

9.4.1 Power-Down (PD)

The device supports power-down control using an external power-down (PDx) pin or by writing a logic high to bit 6 of SPI register 2h (see the *Register Maps* section). The external PDx pins are active high: when left floating. the device defaults to an on condition resulting from the internal pulldown resistors that cause a logic low on the PDx pins. The device PDx thresholds are noted in the *Electrical Characteristics* table. The device consumes approximately 7 mA in power-down mode. Note that the SPI register contents are preserved in power-down mode.

9.4.2 Gain Control

The LMH2832 gain can be controlled from 30-dB gain (0-dB attenuation) to -9-dB gain in 1-dB steps by digitally programming the SPI register 2h; see the Register Maps section for more details.

9.5 Programming

9.5.1 Details of the Serial Interface

The LMH2832 has a set of internal registers that can be accessed by the serial interface formed by the CS (serial interface enable), SCLK (serial interface clock), SDI (serial interface input data), and SDO (serial interface read-back data) pins. Serially shifting bits into the device is enabled when $\overline{\text{CS}}$ is low. SDI serial data are latched at every SCLK rising edge when $\overline{\text{CS}}$ is active (low). The serial data are loaded into the register at every 16th SCLK rising edge when CS is low. When the word length exceeds a multiple of 16 bits, the excess bits are ignored. Data can be loaded in multiples of 16-bit words within a single active \overline{CS} pulse. The first eight bits form the register address and the remaining eight bits are the register data. The interface can function with SCLK frequencies from 25 MHz down to very low speeds (of a few hertz) and also with a non-50% SCLK duty cycle. A summary of the LMH2832 SPI protocol is:

- 1. SPI-1.1 interface
- Independent channel A, B attenuation programming (6-bit gain control)
- 3. SPI register contents are preserved in power-down mode
- SPI-controlled power modes (3-bit control for eight options to step down the power)
- 5. Powered for the main 5-V power supply
- 6. 1.8-V logic

Product Folder Links: LMH2832

Copyright © 2016, Texas Instruments Incorporated

Submit Documentation Feedback



Programming (continued)

9.5.2 Timing Diagrams

Figure 45 and Figure 46 show timing diagrams for the SPI write and read bus cycles, respectively. Figure 47 shows an example timing diagram for a streaming write cycle and Figure 48 shows an example timing diagram for a streaming read cycle. Figure 49, Figure 50, Figure 51, and Figure 52 illustrate timing diagrams and requirements for the clock, data input, data output, and chip select, respectively. See the *Timing Requirements: SPI* table for SPI timing requirements.

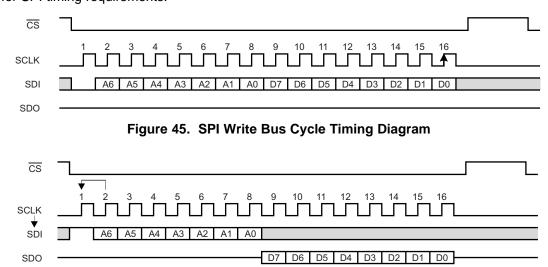


Figure 46. SPI Read Bus Cycle Timing Diagram

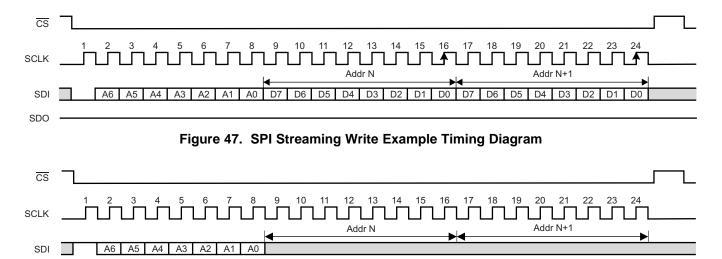


Figure 48. SPI Streaming Read Example Timing Diagram

D7 D6 D5 D4 D3 D2 D1 D0 D7 D6 D5 D4 D3 D2 D1 D0

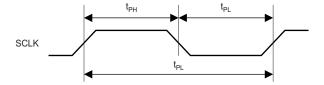


Figure 49. SPI Clock Timing Diagram

Product Folder Links: LMH2832

SDO



Programming (continued)

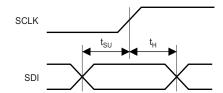


Figure 50. SPI Data Input Timing Diagram

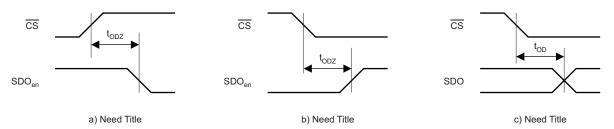


Figure 51. SPI Data Output Timing Diagrams

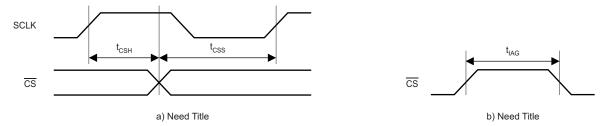


Figure 52. SPI Chip Select Timing Diagrams

9.6 Register Maps

Table 3 shows the SPI registers for the LMH2832.

Table 3. SPI Register Map

ADDRESS		DEFAULT					REGISTI	ER DATA			
(A[6:0])	R/W	(Hex)	REGISTER NAME	7	6	5	4	3	2	1	0
0	R	В3	Revision ID	1	0	1	1	0	0	1	1
1	R	23	Product ID	0	0	1	0	0	0	1	1
2	R/W	00	SW reset		Reserved		Reset B		Reserved		Reset A
3	R/W	00	Power-down	Reserved			PD B	Reserved F		PD A	
4	R/W	20	Channel A RW0, bias control				Channel A RW0				
5	R/W	14	Channel A RW1, attenuator control				Channe	I A RW1			
6	R/W	20	Channel B RW0, bias control	Channel B RW0							
7	R/W	14	Channel B RW1, attenuator control	Channel B RW1		I B RW1					
8-127	R	00	Reserved	0	0	0	0	0	0	0	0



9.6.1 Register Descriptions

Exercising the SW reset function returns all registers to the default values of the respective channel.

9.6.1.1 SW Reset Register (address = 2)

Figure 53. SW Reset Register

7	6	5	4	3	2	1	0
	Reserved		Reset B		Reserved		Reset A
	R-0h		R/W-0h		R-0h		R/W-0h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

Table 4. SW Reset Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-5	Reserved	R	0h	Reserved.
4	Reset B	R/W	Oh	This bit is a self-clearing bit. 0 = No action 1 = Reset
3-1	Reserved	R	0h	Reserved.
0	Reset A	R/W	0h	This bit is a self-clearing bit. 0 = No action 1 = Reset

9.6.2 Power-Down Control Register (address = 3)

Figure 54. Power-Down Control Register

7	6	5	4	3	2	1	0
	Reserved		PD B		Reserved		PD A
	R-0h		R/W-0h		R-0h		R/W-0h

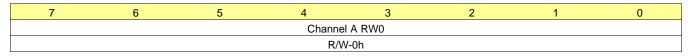
LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

Table 5. Power-Down Control Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-5	Reserved	R	0h	Reserved.
4	PD B	R/W	0h	0 = Active 1 = PD
3-1	Reserved	R	0h	Reserved.
0	PD A	R/W	0h	0 = Active 1 = PD

9.6.3 Channel A RW0 Register (address = 4)

Figure 55. Channel A RW0 Register



LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

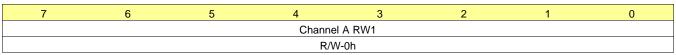
Table 6. Channel A RW0 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-0	Channel A RW0	R/W	0h	These bits drive the output CHA_RW0[7:0] and are reset by a device reset or Reset A. Table 10 lists controls for this register.



9.6.4 Channel A RW1 Register (address = 5)

Figure 56. Channel A RW1 Register



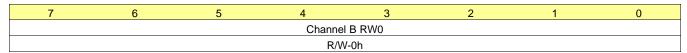
LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

Table 7. Channel A RW1 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-0	Channel A RW1	R/W	0h	These bits drive the output CHA_RW1[7:0] and are reset by a device reset or Reset A. Table 11 lists controls for this register.

9.6.5 Channel B RW0 Register (address = 6)

Figure 57. Channel B RW0 Register



LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

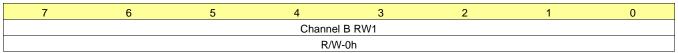
Table 8. Channel B RW0 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-0	Channel B RW0	R/W		These bits drive the output CHB_RW0[7:0] and are reset by a device reset or Reset B. Table 10 lists controls for this register.



9.6.6 Channel B RW1 Register (address = 7)

Figure 58. Channel B RW1 Register



LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

Table 9. Channel B RW1 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7-0	Channel B RW1	R/W		These bits drive the output CHB_RW1[7:0] and are reset by a device reset or Reset B. Table 11 lists controls for this register.

Table 10. Bias Control Register Bit Settings (Channels A, B)⁽¹⁾

7	6	5	4	3	2	1	0
0	0	0	0	0	0	0	0
0	0	0	0	0	0	0	1
0	0	0	0	0	0	1	X
0	0	0	0	0	1	X	X
0	0	0	0	1	X	X	X
0	0	0	1	X	X	X	X
0	0	1	X	X	X	X	X
0	1	X	X	X	X	X	X
1	X	X	X	X	X	X	X

⁽¹⁾ Default value: 001xxxxx. Highest power: 1xxxxxxx. Lower power: 00000000.



Table 11. Attenuator Control Register Bit Settings (Channels A, B)⁽¹⁾

	i i. Attenuator			9- (, - ,	
7 6	5	4	3	2	1	0
Reserved, always read 0	0	0	0	0	0	0
Reserved, always read 0	0	0	0	0	0	1
Reserved, always read 0	0	0	0	0	1	0
Reserved, always read 0	0	0	0	0	1	1
Reserved, always read 0	0	0	0	1	0	0
Reserved, always read 0	0	0	0	1	0	1
Reserved, always read 0	0	0	0	1	1	0
Reserved, always read 0	0	0	0	1	1	1
Reserved, always read 0	0	0	1	0	0	0
Reserved, always read 0	0	0	1	0	0	1
Reserved, always read 0	0	0	1	0	1	0
Reserved, always read 0	0	0	1	0	1	1
Reserved, always read 0	0	0	1	1	0	0
Reserved, always read 0	0	0	1	1	0	1
Reserved, always read 0	0	0	1	1	1	0
Reserved, always read 0	0	0	1	1	1	1
Reserved, always read 0	0	1	0	0	0	0
Reserved, always read 0	0	1	0	0	0	1
Reserved, always read 0	0	1	0	0	1	0
Reserved, always read 0	0	1	0	0	1	1
Reserved, always read 0	0	1	0	1	0	0
Reserved, always read 0	0	1	0	1	0	1
Reserved, always read 0	0	1	0	1	1	0
Reserved, always read 0	0	1	0	1	1	1
Reserved, always read 0	0	1	1	0	0	0
Reserved, always read 0	0	1	1	0	0	1
Reserved, always read 0	0	1	1	0	1	0
Reserved, always read 0	0	1	1	0	1	1
Reserved, always read 0	0	1	1	1	0	0
Reserved, always read 0	0	1	1	1	0	1
Reserved, always read 0	0	1	1	1	1	0
Reserved, always read 0	0	1	1	1	1	1
Reserved, always read 0	1	0	0	0	0	0
Reserved, always read 0	1	0	0	0	0	1
Reserved, always read 0	1	0	0	0	1	0
Reserved, always read 0	1	0	0	0	1	1
Reserved, always read 0	1	0	0	1	0	0
Reserved, always read 0	1	0	0	1	0	1
Reserved, always read 0	1	0	0	1	1	0
Reserved, always read 0	1	0	0	1	1	1

⁽¹⁾ Default attenuation setting: xx001011. Maximum attenuation (lowest gain setting): xx100111. Minimum attenuation (highest gain setting): xx000000.



10 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

The LMH2832 is designed as a general-purpose, analog-to-digital converter (ADC) driver that also meets the performance requirements for DOCSIS 3.X upstream CMTS solutions. This section describes various requirements and considerations for using the LMH2832 and also some design examples.

10.1.1 Driving ADCs

When the amplifier is driving an ADC, the key points to consider for implementation are the signal-to-noise ratio (SNR), spurious-free dynamic range (SFDR), and ADC input considerations, as described in this section.

A typical application of the LMH2832 involves driving a wideband, 14-bit ADC (such as the ADS54J40), as shown in Figure 59. The LMH2832 can drive the full Nyquist bandwidth of ADCs with sampling rates up to 900 MSPS. If the front-end bandwidth of the ADC is more than 450 MHz, then use a simple noise filter to improve SNR. Otherwise, the ADC can be connected directly to the amplifier output pins with appropriate matching resistors to limit the full-scale input of the ADC. Note that the LMH2832 inputs must be driven differentially using a balun or fully differential amplifiers (FDAs). For dc-coupled applications, an FDA (such as the LMH3401 or LMH5401) that can convert a single-ended input to a differential output with low distortion is preferred.

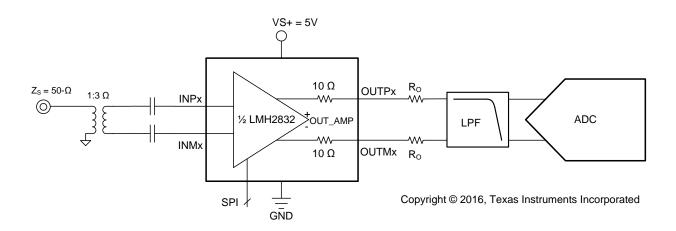


Figure 59. ADC Driver with a 50- Ω Source



Application Information (continued)

10.1.1.1 SNR Considerations

When using the LMH2832 with a filter, the signal-to-noise ratio (SNR) of the amplifier and filter can be calculated from the amplitude of the signal and the bandwidth of the filter. The noise from the amplifier is band-limited by the filter with the equivalent brick-wall filter bandwidth. The amplifier and filter noise can be calculated using Equation 3:

$$SNR_{AMP+FILTER} = 10 \cdot log \left[\frac{V_O^2}{e_{FILTEROUT}^2} \right] = 20 \cdot log \left[\frac{V_O}{e_{FILTEROUT}} \right]$$

where:

- $e_{FILTEROUT} = e_{NAMPOUT} \sqrt{ENB}$
- $e_{NAMPOUT}$ = the output noise density of the LMH2832 (50.4 nV/ \sqrt{Hz}) at A_V = 30 dB
- ENB = the brick-wall equivalent noise bandwidth of the filter
- V_O = the amplifier output signal

(3)

For example, with a first-order (N = 1) band-pass or low-pass filter with a 1000-MHz cutoff, ENB is 1.57 • f_{-3dB} = 1.57 • 1000 MHz = 1570 MHz. For second-order (N = 2) filters, ENB is 1.22 • f_{-3dB}. When the filter order increases, ENB approaches f_{-3dB} (N = 3 \rightarrow ENB = 1.15 • f_{-3dB}; N = 4 \rightarrow ENB = 1.13 • f_{-3dB}). Both V_O and e_{FILTEROUT} are in RMS voltages. For example, with a 2-V_{PP} (0.707 V_{RMS}) output signal and a 300-MHz, first-order, low-pass filter, the SNR of the amplifier and filter is 56 dB with e_{FILTEROUT} = 50.4 nV/ $\sqrt{\text{Hz}}$ • $\sqrt{471}$ MHz = 1.09 mV_{RMS}.

The SNR of the amplifier, filter, and ADC sum in RMS fashion, as shown in Equation 4 (SNR values in dB):

$$SNR_{SYSTEM} = -20 \cdot log \left[\sqrt{10^{\frac{-SNR_{AMP+FILTER}}{10}} + 10^{\frac{-SNR_{ADC}}{10}}} \right]$$
(4)

This formula shows that if the SNR of the amplifier and filter equals the SNR of the ADC, then the combined SNR is 3 dB lower (worse). Thus, for minimal degradation (< 1 dB) on the ADC SNR, the SNR of the amplifier and filter must be 10 dB greater than the ADC SNR. The combined SNR calculated in this manner is usually accurate to within ±1 dB of the actual implementation.

10.1.1.2 SFDR Considerations

The SFDR of the amplifier is usually set by the second- or third-order harmonic distortion for single-tone inputs, and by the second-order or third-order intermodulation distortion for two-tone inputs. Harmonics and second-order intermodulation distortion can be filtered to some degree, but third-order intermodulation spurs cannot be filtered. The ADC generates the same distortion products as the amplifier, but also generates additional spurs (not harmonically related to the input signal) as a result of sampling and clock feed through.

When the spurs from the amplifier and filter are known, each individual spur can be directly added to the same spur from the ADC, as shown in Equation 5, to estimate the combined spur (spur amplitudes in dBc):

$$HDx_{SYSTEM} = -20 \cdot log \left[10^{\frac{-HDx_{AMP-FILTER}}{20}} + 10^{\frac{-HDx_{ADC}}{20}} \right]$$
(5)

This calculation assumes that the spurs are in phase, but usually provides a good estimate of the final combined distortion.

For example, if the spur of the amplifier and filter equals the spur of the ADC, then the combined spur is 6 dB higher. To minimize the amplifier contribution (< 1 dB) to the overall system distortion, the spur from the amplifier and filter must be approximately 15 dB lower in amplitude than that of the converter. The combined spur calculated in this manner is usually accurate to within ± 6 dB of the actual implementation; however, higher variations can be detected as a result of phase shift in the filter, especially in second-order harmonic performance.



Application Information (continued)

This worst-case spur calculation assumes that the amplifier and filter spur of interest is in phase with the corresponding spur in the ADC, such that the two spur amplitudes can be added linearly. There are two phase-shift mechanisms that cause the measured distortion performance of the amplifier-ADC chain to deviate from the expected performance calculated using Equation 5; one mechanism is the common-mode phase shift and the other is the differential phase shift.

Common-mode phase shift is the phase shift detected equally in both branches of the differential signal path including the filter. Common-mode phase shift nullifies the basic assumption that the amplifier, filter, and ADC spur sources are in phase. This phase shift can lead to better performance than predicted when the spurs become phase shifted, and there is the potential for cancellation when the phase shift reaches 180°. However, there is a significant challenge in designing an amplifier-ADC interface circuit to take advantage of a common-mode phase shift for cancellation: the phase characteristics of the ADC spur sources are unknown, thus the necessary phase shift in the filter and signal path for cancellation is also unknown.

Differential phase shift is the difference in the phase response between the two branches of the differential filter signal path. Differential phase shift in the filter is a result of mismatched components caused by nominal tolerances and can severely degrade the even harmonic distortion of the amplifier-ADC chain. This effect has the same result as mismatched path lengths for the two differential traces, and causes more phase shift in one path than the other. Ideally, the phase responses over frequency through the two sides of a differential signal path are identical, such that even harmonics remain optimally out of phase and cancel when the signal is taken differentially. However, if one side has more phase shift than the other, then the even harmonic cancellation is not as effective.

Single-order, resistor-capacitor (RC) filters cause very little differential phase shift with nominal tolerances of 5% or less, but higher-order, inductor-capacitor (LC) filters are very sensitive to component mismatch. For instance, a third-order Butterworth band-pass filter with a 100-MHz center frequency and a 20-MHz bandwidth displays as much as 20° of differential phase imbalance in a SPICE Monte Carlo analysis with 2% component tolerances. Therefore, although a prototype may work, production variance is unacceptable. For ac-coupled or dc-coupled applications where a transformer or balun cannot be used, using first- or second-order filters is recommended to minimize the effect of differential phase shift.

10.1.1.3 ADC Input Common-Mode Voltage Considerations (AC-Coupled Input)

When interfacing to an ADC, the input common-mode voltage range of the ADC must be taken into account for proper operation. In an ac-coupled application between the amplifier and the ADC, the input common-mode voltage bias of the ADC can be accomplished in different ways. Some ADCs use internal bias networks such that the analog inputs are automatically biased to the required input common-mode voltage if the inputs are accoupled with capacitors (or if the filter between the amplifier and ADC is a band-pass filter). Other ADCs supply the required input common-mode voltage from a reference voltage output pin (often termed CM or V_{CM}). With these ADCs, the ac-coupled input signal can be re-biased to the input common-mode voltage by connecting resistors from each input to the CM output of the ADC, as shown in Figure 60. AC coupling provides dc common-mode isolation between the amplifier and the ADC; thus, the output common-mode voltage of the amplifier is a don't care for the ADC.

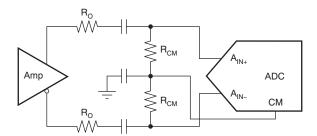


Figure 60. Biasing AC-Coupled ADC Inputs Using the ADC CM Output



Application Information (continued)

10.1.1.4 ADC Input Common-Mode Voltage Considerations (DC-Coupled Input)

The LMH2832 is designed to primarily be used in ac-coupled applications only. However, the LMH2832 can be dc-coupled if certain strict conditions are met. The LMH2832 has an internal common-mode bias equal to the mid-supply voltage, so any dc coupling on the input or output must have a common-mode voltage that is also set to mid-supply. To dc couple to an ADC input, the mid-supply voltage of the LMH2832 must be centered around the ADC input common-mode. This common-mode matching can be accomplished by shifting the supplies to center the mid-supply voltage around the ADC input common-mode voltage. However, shifting the supplies also changes the ground reference for the digital inputs, which then likely requires a voltage-shifted interface as well. The LMH2832 is not recommended to be operated as dc-coupled unless absolutely necessary.

10.2 Typical Applications

10.2.1 DOCSIS 3.X Driver

The LMH2832 is designed to perform best when driving differential input ADCs in high-speed applications. Figure 61 shows an example diagram of the LMH2832 driving an ADC with a fifth-order, low-pass filter for a 75- Ω impedance, data over cable service interface specification (DOCSIS) 3.X upstream receiver return path application. The primary interface between the amplifier and the ADC is usually an antialiasing filter to suppress high-frequency harmonics that otherwise alias back into the ADC FFT spectrum. Filters range from single-order real RC poles to higher-order, resistor-inductor-capacitor (RLC) filters, depending on the application requirements. Series output resistors (R_O) help isolate the amplifier from any capacitive load presented by the filter, and can also be used to create a matched impedance to drive transmission lines.

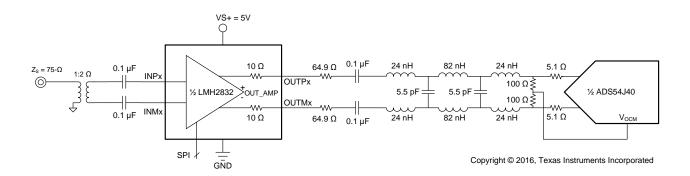


Figure 61. DOCSIS 3.X Driver with the ADS54J40 and a 300-MHz, 4th-Order, Butterworth, Low-Pass Filter

10.2.1.1 Design Requirements

Table 12 shows example design requirements for the LMH2832 in an upstream receiver application.

Table 12. Example Design Requirements

SPECIFICATION	DESIGN REQUIREMENTS			
Supply voltage	4.75 to 5.25 V			
Usable input frequency range	300 MHz			
System voltage gain and range	33-dB voltage gain with 30-dB range			
Source impedance	75 Ω , single-ended			
Signal path SNR at 175 MHz (measured at ADC)	> 50 dBFS			



10.2.1.2 Detailed Design Procedure

To begin the design process, make sure that none of the following design parameters exceed the limits listed in the *Electrical Characteristics* table, such as:

- Supply voltage
- Temperature range
- Input voltage range across gain
- Output current requirements
- Digital I/O voltages and currents

10.2.1.2.1 Source Resistance Matching

Standard DOCSIS systems use a characteristic single-ended impedance of 75 Ω that must be properly matched to the 150- Ω differential impedance of the LMH2832. The circuit in Figure 61 uses a transformer with a 1:2- Ω ratio to convert the signal from single-ended to differential, and also to match the differential impedance. The transformer also adds a signal gain of approximately 3 dB to the system with some insertion loss depending on the chosen transformer.

10.2.1.2.2 Output Impedance Matching

For the circuit in Figure 61, the output impedance is matched to a 150- Ω characteristic impedance filter to maximize the performance of the LMH2832. On the amplifier output side, the output impedance is matched to 150 Ω by including a 65- Ω series resistor on each output. Combined with the internal 10- Ω resistors on each output, the total differential impedance becomes 150 Ω . The ADS54J40 has an input impedance of approximately 600 Ω that is reduced to 150 Ω by using two 5- Ω series input resistors in parallel with two 100- Ω series resistors. The 5- Ω series resistors are included to isolate the input capacitance of the ADC so that the response of the filter is not affected. With both the amplifier and ADC impedances matched, any transmission line effects of the connection are minimized.

If the ADC is physically located close enough to the amplifier, a matched impedance may not be needed; see *Driving Low Insertion-Loss Filters* section for more information on driving non-matched filters.

10.2.1.2.3 Voltage Headroom Considerations

Because of the series resistors included on both the amplifier outputs and ADC inputs, the amplifier must drive a voltage that is significantly higher than the ADC full-scale input. For the circuit in Figure 61, the ADS54J40 full-scale input voltage is 1.9 V_{PP} , so the required voltage at the amplifier output pins is 3.6 V_{PP} . This voltage is less than the specified output voltage of 5 V_{PP} for the LMH2832, thus system performance is not limited. If the required output voltage is higher than what the amplifier can support, then the matched resistance value can be reduced. However, this reduction can have performance implications because more current output is required from the amplifier.

The input voltage swing can be larger than the output voltage swing because the LMH2832 can operate as an attenuator. To maintain the full-scale voltage of the ADS54J40 input in this application, the amplifier cannot attenuate more than 1 dB from input to output; otherwise, the maximum input voltage swing is exceeded. If the amplifier must be operated with more attenuation, then the output voltage must be reduced.

10.2.1.3 Application Curve

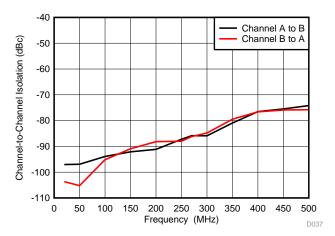
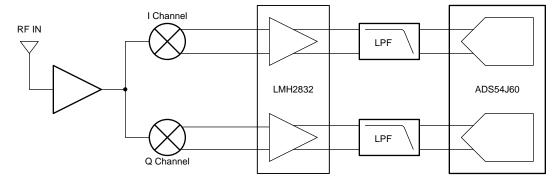


Figure 62. Amplifier Dual Channel Isolation Presented to ADC Interface

10.2.2 IQ Receiver

The LMH2832 is a dual-channel device; therefore, the device has excellent gain and phase matching between channels A and B. This matching makes the LMH2832 an excellent choice for systems that require two matched channels (such as an IQ demodulation receiver), as shown in Figure 63. For an IQ system, both the gain and phase must match for the real and imaginary channel. When using two single-channel amplifiers, the matching characteristics are subject to process lot and packaging variations for two individual devices, and there is often no way to make sure that the amplifiers match without testing each amplifier. However, the dual-channel architecture of the LMH2832 allows for much tighter gain and phase matching with minimal crosstalk effects. For more matching information, see the *Electrical Characteristics* table.



Copyright © 2016, Texas Instruments Incorporated

Figure 63. IQ Receiver Block Diagram



10.3 Do's and Don'ts

10.3.1 Do:

- Include a thermal analysis at the beginning of the project
- · Use well-terminated transmission lines for all signals
- Maintain symmetrical input and output trace layouts
- Use solid metal layers for the power supplies
- · Keep signal lines as straight as possible

10.3.2 Don't:

- Use a lower power-supply voltage than necessary
- Forget about the common-mode response of filters and transmission lines
- · Rout digital line traces close to the analog signals and supply line traces

11 Power Supply Recommendations

The LMH2832 is designed to be used with a single supply with a range of 4.75 V to 5.25 V. The ideal supply voltage is a 5.0-V total single-ended supply. If the supply is reduced to the minimum voltage, then the maximum input and output voltage range is reduced by 0.25 V.

11.1 Split Supplies

Ideally, the LMH2832 uses a single-ended, 5-V supply, but the device can be operated on a split supply if necessary. However, the digital logic is referenced to the GND pins, meaning that the logic reference shifts with the GND supply if connected to a negative voltage and must be accounted for in the logic connections. In general, the LMH2832 is not suggested to be operated with a split-supply configuration.

11.2 Supply Decoupling

Power-supply decoupling is critical to high-frequency performance. Onboard bypass capacitors are used on the LMH2832EVM; however, the most important component of the supply bypassing is provided by the printed circuit board (PCB). As illustrated in Figure 64, there are multiple vias connecting the LMH2832 power planes to the power-supply traces. These vias connect the internal power planes to the LMH2832. Both $V_{\rm CC}$ and GND must be connected to the internal power planes with several square centimeters of continuous plane in the immediate vicinity of the amplifier. The capacitance between these power planes provides the bulk of the high-frequency bypassing for the LMH2832.



12 Layout

12.1 Layout Guidelines

With a small bandwidth greater than 1 GHz, layout for the LMH2832 is critical and nothing can be neglected. In order to simplify board design, the LMH2832 has on-chip resistors that reduce the affect of off-chip capacitance. For this reason, make sure that the ground layer below the LMH2832 is not cut. The recommendation to not cut the ground plane under the amplifier input and output pins is different than many other high-speed amplifiers, but the reason is that parasitic inductance is more harmful to the LMH2832 performance than parasitic capacitance. By leaving the ground layer under the device intact, parasitic inductance of the output and power traces is minimized. The DUT portion of the evaluation board layout is shown in Figure 64.

The EVM uses long-edge capacitors for the decoupling capacitors, which reduces series resistance and increases the resonant frequency. Vias are also placed to the power planes before the bypass capacitors. Although not evident in the top layer, two vias are used at the capacitor in addition to the two vias underneath the device.

The output-matching resistors are 0402 size and are placed very close to the amplifier output pins, which reduces both parasitic inductance and capacitance. The use of 0603 output-matching resistors produces a measurable decrease in bandwidth.

When the signal is on a $50-\Omega$ or $75-\Omega$ controlled impedance transmission line, the layout then becomes much less critical. The transition from the $50-\Omega$ or $75-\Omega$ transmission line to the amplifier pins is the most critical area.

12.2 Layout Example

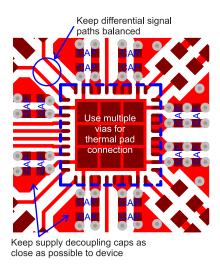


Figure 64. Layout Example



13 Device and Documentation Support

13.1 Device Support

13.1.1 Device Nomenclature

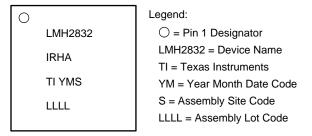


Figure 65. Device Marking Information

13.2 Documentation Support

13.2.1 Related Documentation

For related documentation see the following:

- ADS54J40 Dual-Channel, 14-Bit, 1.0-GSPS Analog-to-Digital Converter Data Sheet (SBAS714)
- LMH3401 7-GHz, Ultra-Wideband, Fixed-Gain, Fully-Differential Amplifier Data Sheet (SBOS695)
- LMH5401 8-GHz, Low-Noise, Low-Power, Fully-Differential Amplifier Data Sheet (SBOS710)
- LMH6521 High Performance Dual DVGA Data Sheet (SNOSB47)
- LMH3404 Dual-Channel, 7-GHz, Low-Noise, Low-Power, Fully Differential Amplifier Data Sheet (SBOS739)
- LMH3402 Dual, Selectable-Gain, 7-GHz, Low-Noise, Low-Power, Fully Differential Amplifier Data Sheet (SBOS744)
- LMH2832EVM-50 Evaluation Module User's Guide (SLOU454)
- LMH2832EVM-75 Evaluation Module User's Guide (SLOU438)
- LMH2832 TINA-TI Reference Design (SBOMA21)
- LMH2832 TINA-TI Spice Model (SBOMA22)

13.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

13.4 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

13.5 Trademarks

E2E is a trademark of Texas Instruments.

Keysight Technologies is a trademark of Keysight Technologies.

SPI is a trademark of Motorola Mobility LLC.

All other trademarks are the property of their respective owners.



13.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

13.7 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

www.ti.com

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LMH2832IRHAR	ACTIVE	VQFN	RHA	40	2500	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	LMH2832 IRHA	Samples
LMH2832IRHAT	ACTIVE	VQFN	RHA	40	250	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	LMH2832 IRHA	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.





10-Dec-2020

PACKAGE MATERIALS INFORMATION

www.ti.com 22-Jul-2016

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMH2832IRHAR	VQFN	RHA	40	2500	330.0	16.4	6.3	6.3	1.1	12.0	16.0	Q2
LMH2832IRHAT	VQFN	RHA	40	250	180.0	16.4	6.3	6.3	1.1	12.0	16.0	Q2

www.ti.com 22-Jul-2016



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMH2832IRHAR	VQFN	RHA	40	2500	367.0	367.0	38.0
LMH2832IRHAT	VQFN	RHA	40	250	210.0	185.0	35.0

6 x 6, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





- NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
 - B. This drawing is subject to change without notice.
 - C. QFN (Quad Flatpack No-Lead) Package configuration.
 - D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
 - E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 - F. Package complies to JEDEC MO-220 variation VJJD-2.



RHA (S-PVQFN-N40)

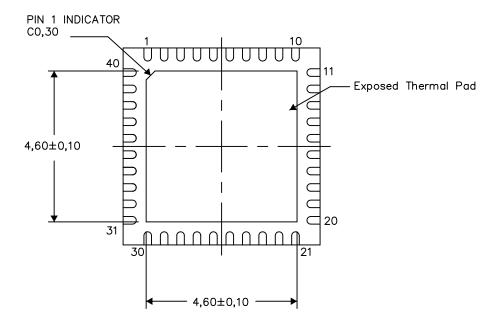
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

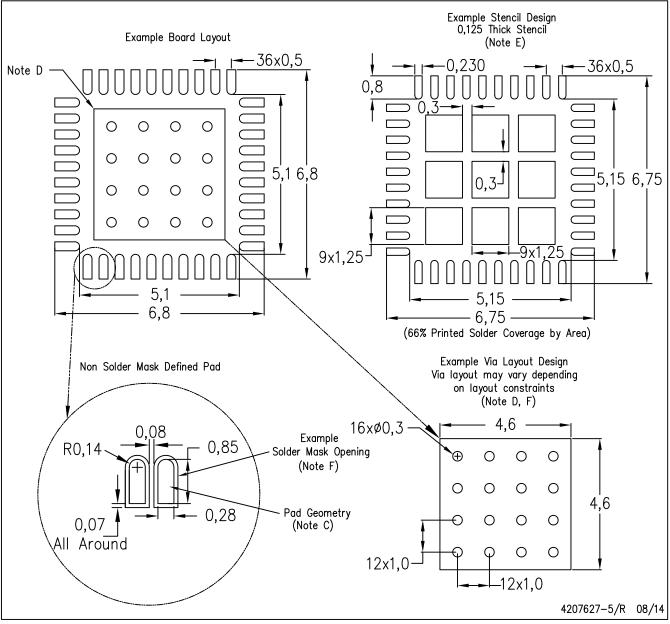
4206355-5/X 08/14

NOTES: A. All linear dimensions are in millimeters



RHA (S-PVQFN-N40)

PLASTIC QUAD FLATPACK NO-LEAD



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (https://www.ti.com/legal/termsofsale.html) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2021, Texas Instruments Incorporated